

SMBF Plastic-Encapsulate Diodes

Fast Recovery Rectifier Diode

Features

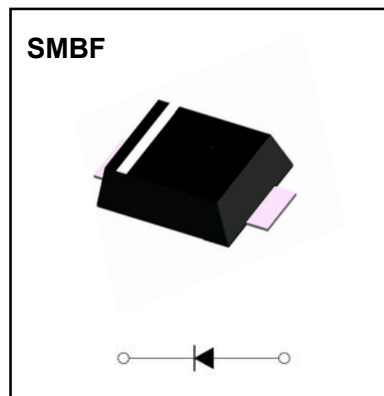
- I_O 2A
- V_{RRM} 50V-1000V
- High surge current capability
- Glass passivated chip
- Polarity: Color band denotes cathode

Applications

- Rectifier

Marking

- RS2ABF-RS2MBF : RS2AB-RS2MB



Limiting Values (Absolute Maximum Rating)

Item	Symbol	Unit	Test Conditions	RS2						
				ABF	BBF	DBF	GBF	JBF	KBF	MBF
Repetitive Peak Reverse Voltage	V_{RRM}	V		50	100	200	400	600	800	1000
Maximum RMS Voltage	V_{RMS}	V		35	70	140	280	420	560	700
Average Forward Current	$I_{F(AV)}$	A	60Hz Half-sine wave, Resistance load, $T_a=75^\circ\text{C}$	2.0						
Surge(Non-repetitive)Forward Current	I_{FSM}	A	60Hz Half-sine wave, 1 cycle,	60						
Junction Temperature	T_J	$^\circ\text{C}$		-55~+150						
Storage Temperature	T_{STG}	$^\circ\text{C}$		-55 ~ +150						

Electrical Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

Item	Symbol	Unit	Test Condition		RS2						
					ABF	BBF	DBF	GBF	JBF	KBF	MBF
Peak Forward Voltage	V _F	V	I _F =2.0A		1.3						
Maximum reverse recovery time	t _{rr}	ns	I _F =0.5A,I _R =1.0A,I _{rr} =0.25A		150				250	500	
Peak Reverse Current	I _{RRM1}	μA	V _{RM} =V _{RRM}	T _a =25℃	2.5						
	T _a =125℃			200							
Thermal Resistance(Typical)	R _{θJ-A}	℃/W	Between junction and ambient		50						
	R _{θJ-L}		Between junction and terminal		40						

Notes:

Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas

Typical Characteristics

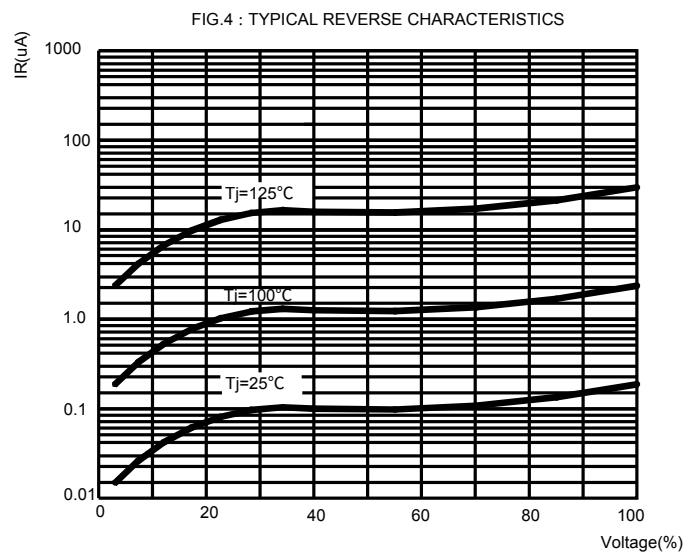
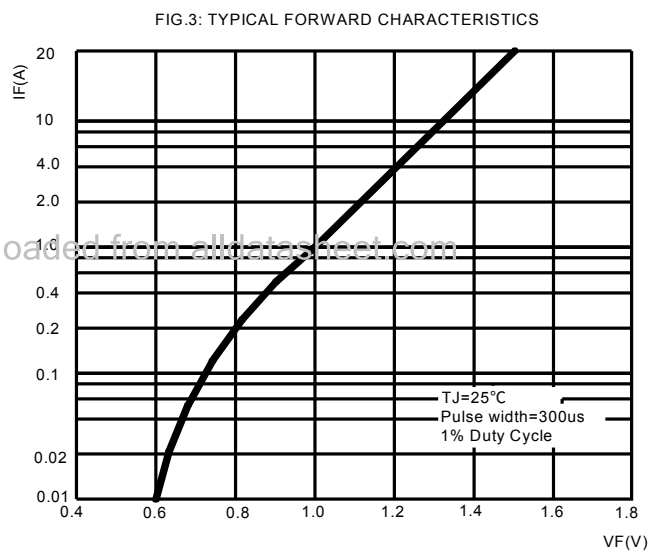
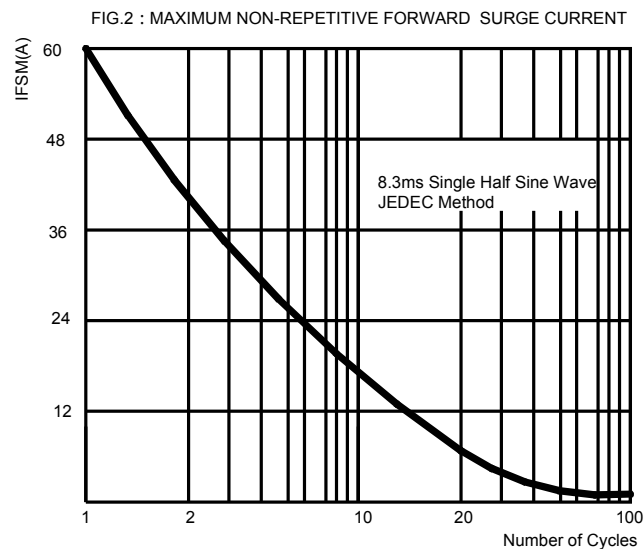
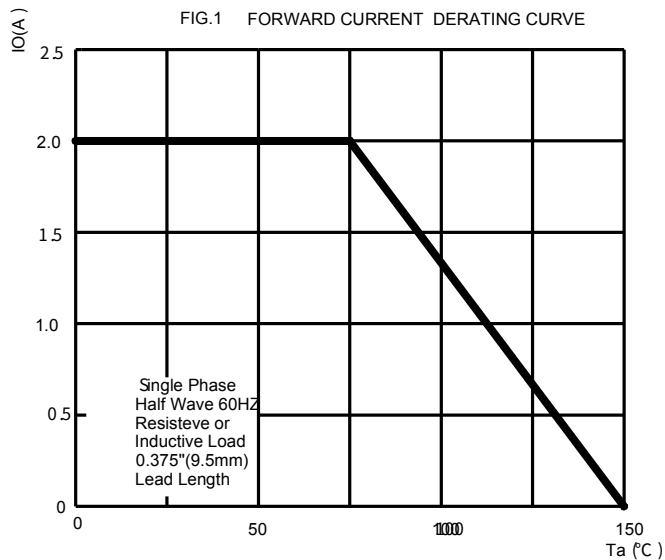
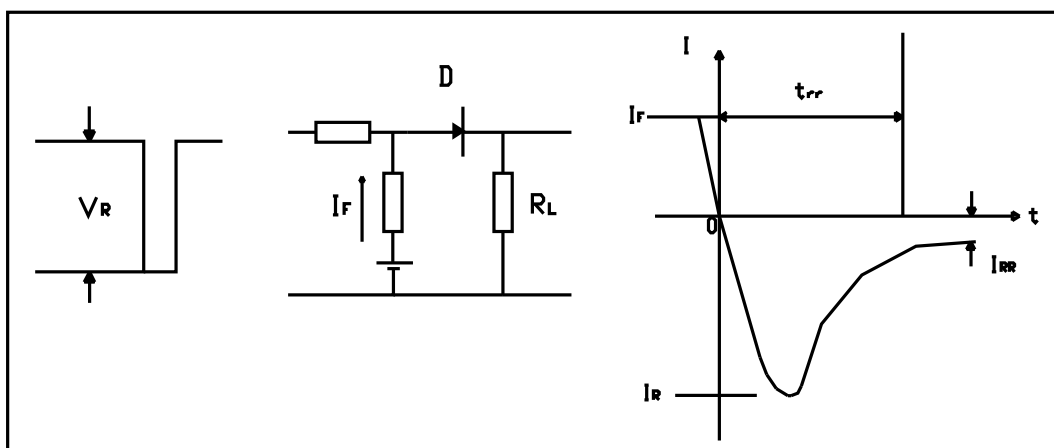
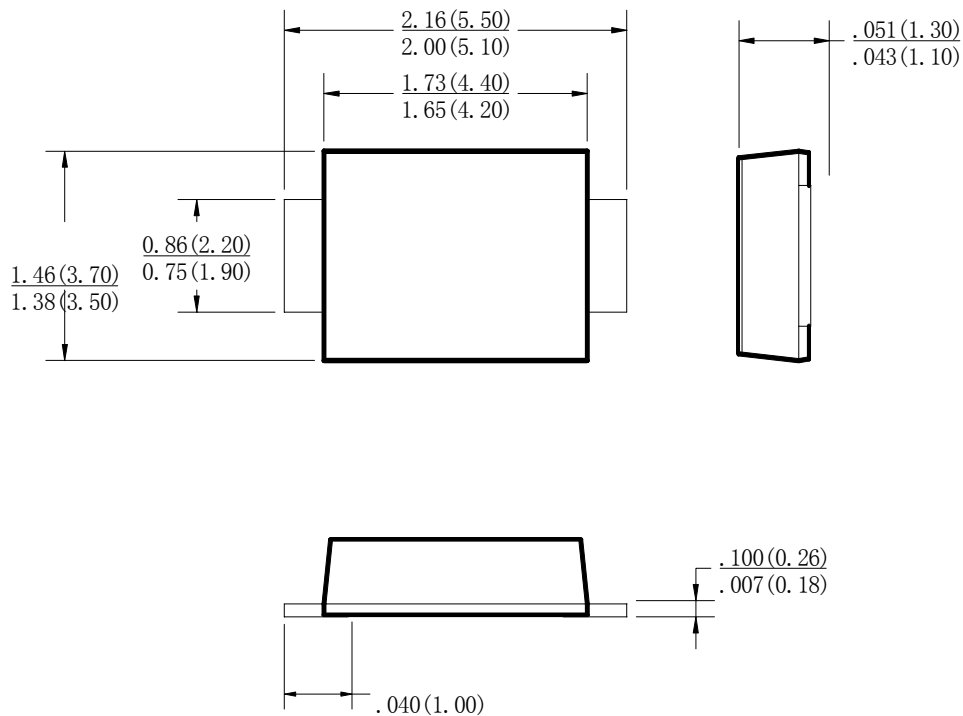


FIG.5 Diagram of circuit and Testing wave form of reverse recovery time



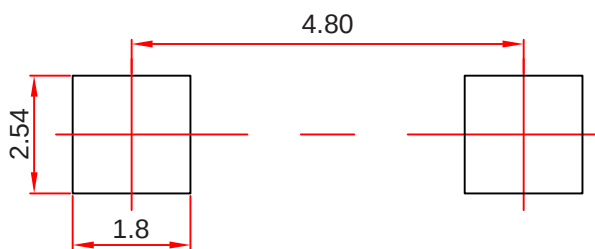
SMBF Package Outline Dimensions



Dimensions in inches and (millimeters)

Downloaded from alldatasheet.com

SMBF Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.05 mm.
3. The pad layout is for reference purposes only.

NOTICE

JSHD reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JSHD does not assume any liability arising out of the application or use of any product described herein.

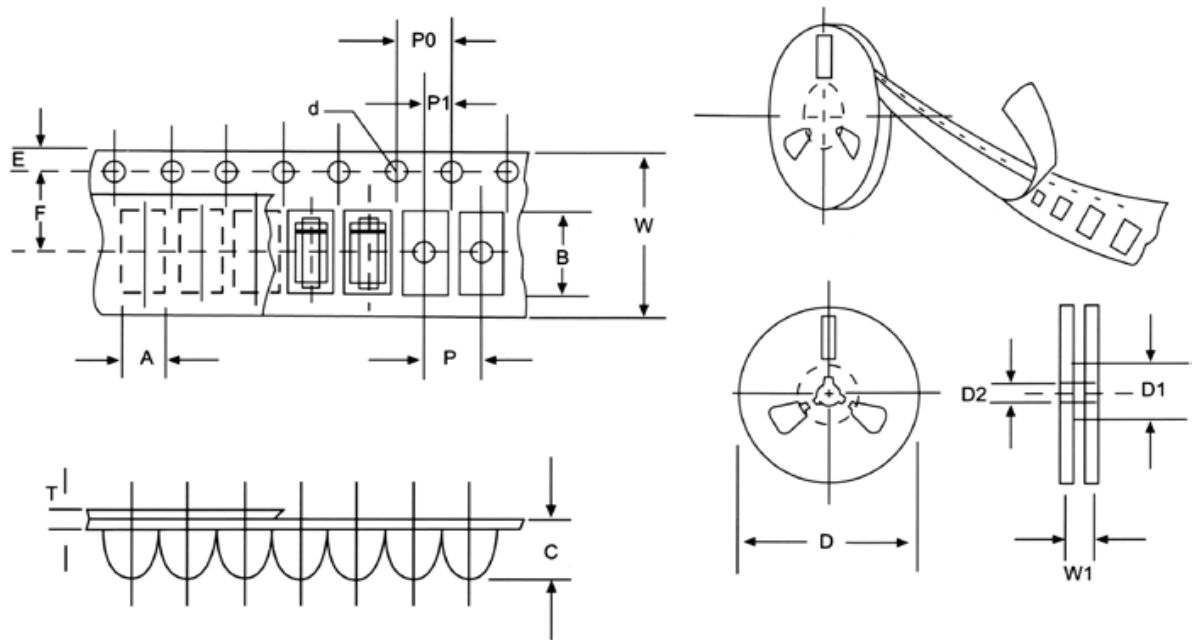


FIG:CONFIGURATION OF AXIAL TAPING

SYMBOL	SYMBOL	SMBF mm(inch)
Carrier width	A	3.80±0.1(0.150±0.004)
Carrier length	B	5.75±0.1(0.226±0.004)
Carrier depth	C	1.40±0.1(0.055±0.004)
Sprocket hole	d	1.55±0.05(0.061±0.002)
Reel outside diameter	D	330/281/178±2.0(13/11/7.0±0.079)
Reel inner diameter	D1	8.0±0.2(0.315±0.008)
Feed hole diameter	D2	13±0.5(0.512±0.020)
Stroket hole position	E	1.75±0.1(0.069±0.004)
Punch hole position	F	5.5±0.05(0.217±0.002)
Punch hole pitch	P	8.0±0.1(0.315±0.004)
Sprocket hole pitch	P0	4.0±0.1(0.157±0.004)
Embossment center	P1	2.0±0.05(0.079±0.002)
Totall tape thickness	T	0.23±0.02 (0.009±0.0008)
Tape width	W	12.0±0.1(0.472±0.004)
Reel width	W1	16.8±2.0(0.661±0.079)

NOTE:Devices are packde in accordance with EIA standard RS-481-A and specification given above.